# 2SC5636

FOR HIGH FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE

### **DESCRIPTION**

Mitsubishi 2SC5636 is a super mini package resin sealed silicon NPN epitaxial transistor. It is designed for high frequency application.

# **FEATURE**

- ·High gain bandwidth product. fT=8.0GHz
- ·High gain,low noise.
- ·Can operate at low voltage.
- ·Super mini package for easy mounting.

# **APPLICATION**

For TV tuners, high frequency amplifier, celluar phone system.

# MAXIMUM RATINGS (Ta=25 )

Symbol	Parameter	Ratings	Unit
Vсво	Collector to Base voltage	15	V
VCEO	Collector to Emitter voltage	6	V
VEBO	Emitter to Base voltage	1.5	V
Ιc	Collector current	50	mA
Pc	Collector dissipation	100	mW
Tj	Junction temperature	+125	
Tstg	Storage temprature	-55~+125	

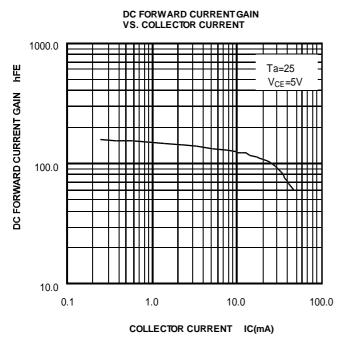
# TERMINAL CONNECTOR ①: BASE ②: EMITTER ③: COLLECTOR

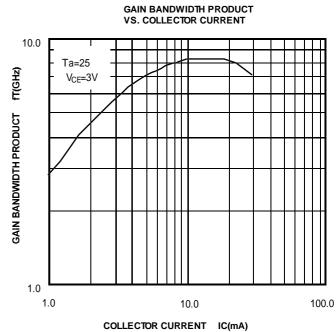
# ELECTRICAL CHARACTERISTICS (Ta=25 )

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Тур	Max	
I сво	Collector cut off current	VCB=10V, I E=0mA			1.0	μA
I ЕВО	Emitter cut off current	VEB=1V, IC=0mA			1.0	μA
hFE	DC forward current gain	VCE=5V, I C=10mA	50		250	
fΤ	Gain bandwidth product	VCE=5V, I E=10mA	5.0	8.0		GHz
Cob	Collector output capacitance	VCB=5V, I E=0mA, f=1MHz		1.0		pF
S <sub>21</sub>   <sup>2</sup>	Insertion power gain	VCE=5V, I C=10mA, f=1GHz	9.0	12.0		dB
NF	Noise figure	VCE=5V, I C=5mA, f=1GHz		1.4		dB

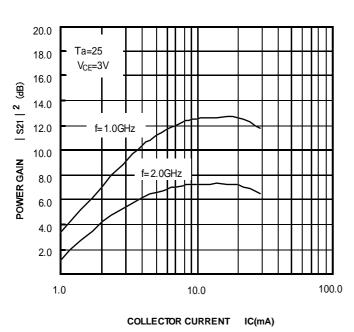
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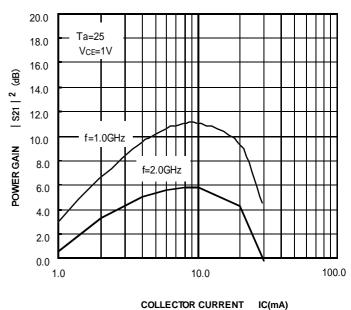




# POWER GAIN VS. COLLECTOR CURRENT



### POWER GAIN VS. COLLECTOR CURRENT



# 2SC5636

FOR HIGH FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE

S PARAMETER									
$V_{CF}=1V,I_{C}=10mA$									
FREQUENCY	<b>0-</b>		<b>S</b> 21		S <sub>1</sub>	2	S <sub>2</sub>	S22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	
500	0.462	-121.3	6.597	102.5	0.087	48.1	0.352	-84.5	
600	0.440	-131.7	5.854	97.0	0.094	48.9	0.320	-87.7	
700	0.434	-143.9	5.029	91.8	0.102	48.7	0.278	-100.6	
800 900	0.423 0.413	-149.9 -155.5	4.569 4.031	88.0 84.1	0.109 0.117	49.7 51.0	0.254 0.233	-101.8 -107.1	
1000	0.407	-159.7	3.685	82.1	0.117	51.3	0.220	-109.7	
1100	0.407	-164.6	3.367	78.5	0.133	51.8	0.211	-114.9	
1200	0.397	-167.5	3.141	76.4	0.140	52.3	0.201	-116.5	
1300 1400	0.395 0.393	-171.3 -173.3	2.880 2.712	73.7 72.2	0.150 0.157	52.8 53.0	0.192 0.187	-120.3 -122.0	
1500	0.389	- 175.3 - 175.7	2.712	69.9	0.157	53.0	0.187	-122.0 -122.4	
1600	0.392	-179.0	2.435	67.0	0.173	53.2	0.176	-124.9	
1700	0.384	179.1	2.307	65.3	0.180	53.0	0.178	-126.3	
1800 1900	0.386 0.383	177.0 174.5	2.178	63.8	0.189	52.8	0.174	-128.4	
2000	0.363	174.5	2.089 2.011	61.8 60.4	0.197 0.204	52.8 52.4	0.175 0.177	-130.4 -131.1	
V <sub>CF</sub> =3V,I <sub>C</sub> =10			2.011	00.1	0.201	02	0.111	10111	
FREQUENCY		S11	S	S21 S12		12 <b>S</b> 2		22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	
500	0.473	-102.1	7.745	108.2	0.076	52.4	0.420	-60.1	
600	0.434	-113.7	6.955	102.1	0.082	53.1	0.389	-62.1	
700 800	0.410 0.391	-127.8 -134.7	6.038 5.488	95.9 92.5	0.089 0.096	52.5 53.4	0.325 0.302	-69.8 -69.2	
900	0.375	-141.5	4.872	87.9	0.104	54.4	0.273	-71.5	
1000	0.365	-146.5	4.457	85.6	0.110	54.7	0.258	-71.7	
1100	0.361	-152.6	4.073	82.1	0.118	55.1	0.242 0.232	-74.8 74.0	
1200 1300	0.350 0.345	-155.8 -160.2	3.805 3.486	79.7 77.1	0.125 0.133	55.7 56.0	0.232	-74.9 -76.7	
1400	0.342	-162.7	3.279	75.5	0.140	56.1	0.213	-77.0	
1500	0.337	-165.4	3.106	73.8	0.147	56.4	0.211	-77.1	
1600	0.337	-169.4	2.928	70.3	0.155	56.2	0.205	-78.4	
1700 1800	0.330 0.332	-171.3 -174.0	2.772 2.617	69.2 67.0	0.161 0.170	56.2 56.3	0.205 0.198	-79.9 -80.6	
1900	0.328	-176.5	2.511	65.2	0.176	56.0	0.197	-82.2	
2000	0.325	-178.4	2.413	63.4	0.184	55.6	0.200	-84.2	
$V_{CE} = 5V, I_{C} = 10$	mA								
FREQUENCY S <sub>11</sub>		S	S21 S12		2	<b>S</b> 22			
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	
500	0.483	-94.6	8.003	110.1	0.071	54.4	0.458	-52.0	
600 700	0.436 0.405	-106.1 -120.3	7.231 6.321	104.2 97.7	0.077 0.085	54.8 54.0	0.428 0.360	-52.8 -59.2	
800	0.381	-127.6	5.738	94.0	0.091	54.8	0.340	-58.2	
900	0.361	-134.6	5.103	89.6	0.099	55.8	0.312	-59.8	
1000	0.349	-139.9	4.683	87.0	0.104	56.3	0.297	-59.2	
1100 1200	0.342 0.330	-146.3 -149.6	4.290 3.990	83.4 81.2	0.112 0.119	56.5 57.0	0.280 0.270	-61.4 -61.6	
1300	0.323	-154.5	3.669	78.4	0.126	57.5	0.256	-61.7	
1400	0.321	-157.2	3.455	76.2	0.133	57.4	0.254	-62.9	
1500	0.314	-160.0	3.273	74.3	0.140	57.6	0.252	-62.7	
1600 1700	0.313 0.305	-164.3 -166.2	3.086 2.915	71.2 70.4	0.147 0.153	57.8 57.4	0.245 0.244	-63.3 -65.4	
1800	0.308	-169.1	2.765	67.9	0.162	57.4	0.240	-66.2	
1900	0.304	-171.9	2.648	65.9	0.169	57.3	0.237	-67.3	
2000	0.299	-173.6	2.538	64.7	0.175	57.0	0.239	-69.1	



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